



Vincotech

10-EY124PA016ME-LP49F18T

datasheet

fastPACK E2 SiC

1200 V / 16 mΩ

Topology features

- Kelvin Emitter for improved switching performance
- Open Emitter configuration
- Temperature sensor

Component features

- High Blocking Voltage with low drain source on state resistance
- High speed SiC-MOSFET technology
- Resistant to Latch-up

Housing features

- Base isolation: Al₂O₃
- Convex shaped substrate for superior thermal contact
- Compact housing
- CTI600 housing material
- Thermo-mechanical push-and-pull force relief
- Press-fit pin
- Reliable cold welding connection

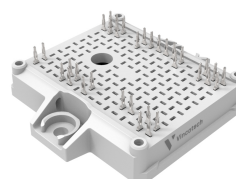
Target applications

- Charging Stations
- Power Supply
- Welding & Cutting

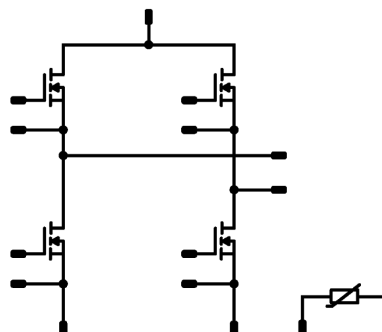
Types

- 10-EY124PA016ME-LP49F18T

flow E2 12 mm housing



Schematic





Vincotech

10-EY124PA016ME-LP49F18T
datasheet

Maximum Ratings

$T_j = 25\text{ °C}$, unless otherwise specified

Parameter	Symbol	Conditions	Value	Unit
Inverter Switch				
Drain-source voltage	V_{DS}		1200	V
Drain current (DC current)	I_D	$T_j = T_{jmax}$ $T_s = 80\text{ °C}$	72	A
Peak drain current	I_{DM}	t_p limited by T_{jmax}	240	A
Total power dissipation	P_{tot}	$T_j = T_{jmax}$ $T_s = 80\text{ °C}$	123	W
Gate-source voltage	V_{GS}	static	-4 / 15	V
		dynamic, AC>1Hz	-8 / 19	
Maximum Junction Temperature	T_{jmax}		175	°C

Module Properties

Thermal Properties

Storage temperature	T_{stg}		-40...+125	°C
Operation temperature under switching condition	T_{jop}		-40...+($T_{jmax} - 25$)	°C

Isolation Properties

Isolation voltage	V_{isol}	DC Test Voltage* $t_p = 2\text{ s}$	6000	V
Creepage distance			>12,7	mm
Clearance			9,14	mm
Comparative Tracking Index	CTI		≥ 600	

*100 % tested in production



Vincotech

10-EY124PA016ME-LP49F18T

datasheet

Characteristic Values

Parameter	Symbol	Conditions						Values			Unit
			V_{GE} [V] V_{GS} [V]	V_{CE} [V] V_{DS} [V] V_F [V]	I_C [A] I_D [A] I_F [A]	T_j [°C]	Min	Typ	Max		

Inverter Switch

Static

Drain-source on-state resistance	$r_{DS(on)}$		15		80	25 125 150	11,2	15,6 20,7 23,1	20,8 ⁽¹⁾	mΩ
Gate-source threshold voltage	$V_{GS(th)}$	$V_{DS} = V_{GS}$			0,023	25	1,8	2,5	3,6	V
Gate to Source Leakage Current	I_{GSS}		15	0		25		20	500	nA
Zero Gate Voltage Drain Current	I_{DSS}		0	1200		25		2	38	μA
Internal gate resistance	r_g							0,85		Ω
Gate charge	Q_g		-4/15	800	80	25		236		nC
Short-circuit input capacitance	C_{iss}	$f = 100 \text{ kHz}$	0	1000	0	25		6714		pF
Short-circuit output capacitance	C_{oss}							258		
Reverse transfer capacitance	C_{rss}							16		
Diode forward voltage	V_{SD}		0		40	25		4,6		V

Thermal

Thermal resistance junction to sink ⁽²⁾	$R_{th(j-s)}$	$\lambda_{paste} = 3,4 \text{ W/mK}$ (PSX)						0,77		K/W
--	---------------	---	--	--	--	--	--	------	--	-----



Vincotech

10-EY124PA016ME-LP49F18T

datasheet

Characteristic Values

Parameter	Symbol	Conditions					Values			Unit	
			V_{GE} [V] V_{GS} [V]	V_{CE} [V] V_{DS} [V] V_F [V]	I_C [A] I_D [A] I_F [A]	T_j [°C]	Min	Typ	Max		
Dynamic											
Turn-on delay time	$t_{d(on)}$	$R_{gon} = 2 \Omega$ $R_{goff} = 2 \Omega$	-4/15	600	64	25		19,84		ns	
						125		18,88			
						150		18,56			
Rise time	t_r					25		6,72		ns	
						125		6,4			
						150		6,4			
Turn-off delay time	$t_{d(off)}$					25		42,24		ns	
						125		44,8			
						150		45,76			
Fall time	t_f					25		9,4		ns	
						125		9,22			
						150		9,44			
Turn-on energy (per pulse)	E_{on}	$Q_{rFWD}=0,776 \mu C$ $Q_{rFWD}=1,06 \mu C$ $Q_{rFWD}=1,17 \mu C$	25		0,365		mWs				
			125		0,35						
			150		0,366						
Turn-off energy (per pulse)	E_{off}		25		0,125		mWs				
			125		0,118						
			150		0,129						
Peak recovery current	I_{RRM}	$di/dt=12690 A/\mu s$ $di/dt=13506 A/\mu s$ $di/dt=13627 A/\mu s$	25		95,84		A				
			125		128,28						
			150		139,79						
Reverse recovery time	t_{rr}		25		15,39		ns				
			125		17,51						
			150		18,71						
Recovered charge	Q_r		25		0,776		μC				
			125		1,06						
			150		1,17						
Reverse recovered energy	E_{rec}		25		0,387		mWs				
			125		0,544						
			150		0,608						
Peak rate of fall of recovery current	$(di_{rr}/dt)_{max}$	25		17483		A/ μs					
		125		27449							
		150		29479							



Vincotech

10-EY124PA016ME-LP49F18T
datasheet

Characteristic Values

Parameter	Symbol	Conditions					Values			Unit
			V_{GE} [V] V_{GS} [V]	V_{CE} [V] V_{DS} [V] V_F [V]	I_C [A] I_D [A] I_F [A]	T_j [°C]	Min	Typ	Max	

Thermistor

Static

Rated resistance	R					25		5		kΩ
Deviation of R100	$\Delta_{R/R}$	$R_{100} = 493 \Omega$				100	-5		5	%
Power dissipation	P							245		mW
Power dissipation constant	d					25		1,4		mW/K
B-value	$B_{(25/50)}$	Tol. $\pm 2 \%$						3375		K
B-value	$B_{(25/100)}$	Tol. $\pm 2 \%$						3437		K
Vincotech Thermistor Reference									K	

⁽¹⁾ Value at chip level

⁽²⁾ Only valid with pre-applied Vincotech thermal interface material.



Vincotech

10-EY124PA016ME-LP49F18T datasheet

Inverter Switch Characteristics

figure 1. MOSFET

Typical output characteristics

$$I_D = f(V_{DS})$$

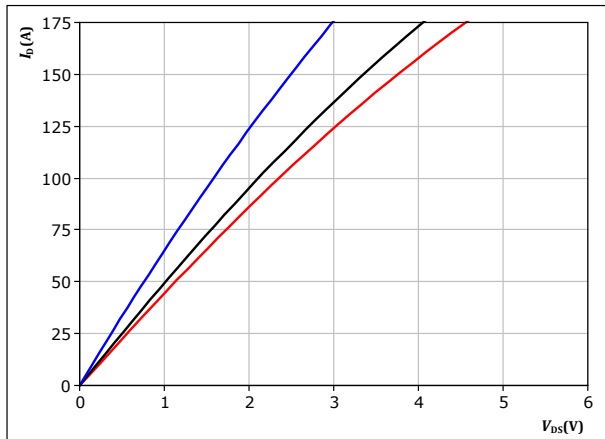


figure 2. MOSFET

Typical output characteristics

$$I_D = f(V_{DS})$$

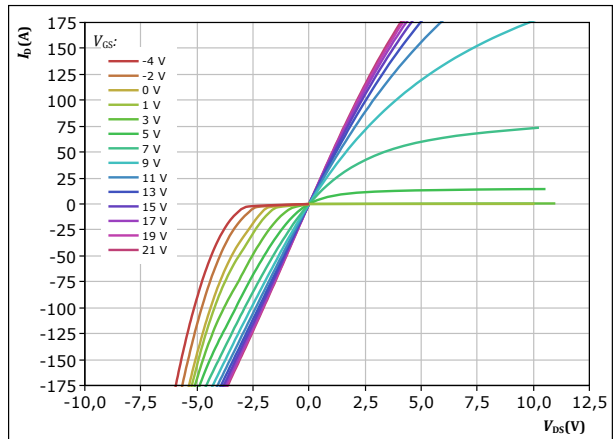


figure 3. MOSFET

Typical transfer characteristics

$$I_D = f(V_{GS})$$

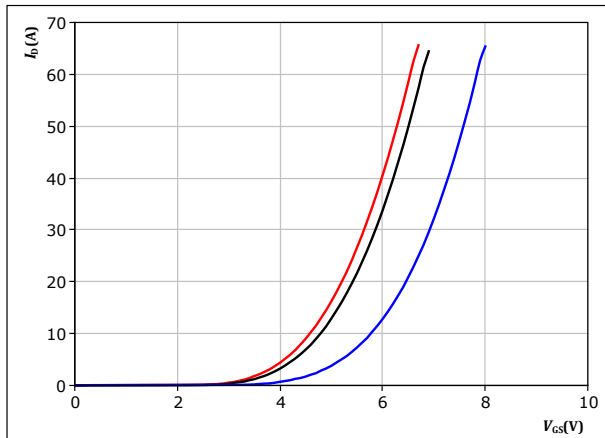
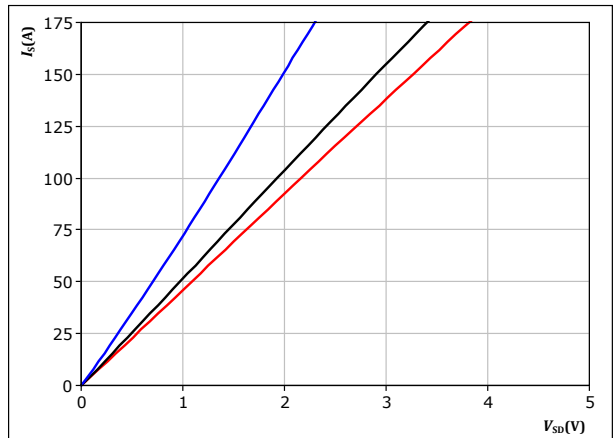


figure 4. MOSFET

Typical reverse drain current characteristics

$$I_{SD} = f(V_{SD})$$





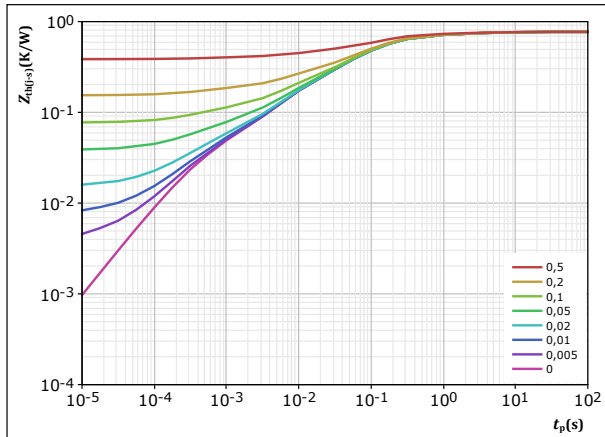
Vincotech

Inverter Switch Characteristics

figure 5. MOSFET

Transient thermal impedance as a function of pulse width

$$Z_{th(j-a)} = f(t_p)$$

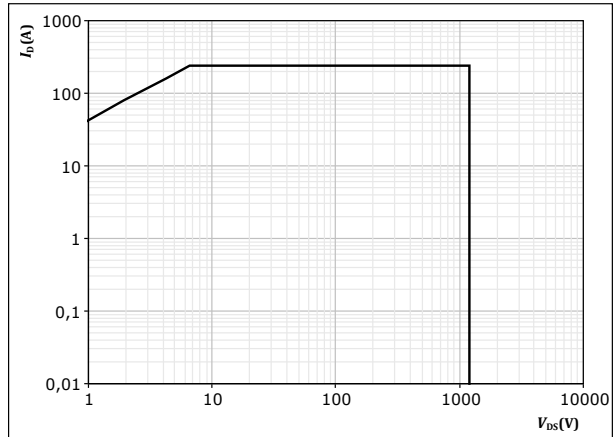


$D =$	t_p / T
$R_{th(j-a)} =$	0,771 K/W
MOSFET thermal model values	
R (K/W)	τ (s)
4,55E-02	4,97E+00
1,35E-01	5,15E-01
4,29E-01	8,73E-02
1,30E-01	8,01E-03
3,16E-02	4,12E-04

figure 6. MOSFET

Safe operating area

$$I_D = f(V_{DS})$$



$D =$	single pulse
$T_s =$	80 °C
$V_{GS} =$	15 V
$T_j =$	T_{jmax}



Vincotech

10-EY124PA016ME-LP49F18T
datasheet

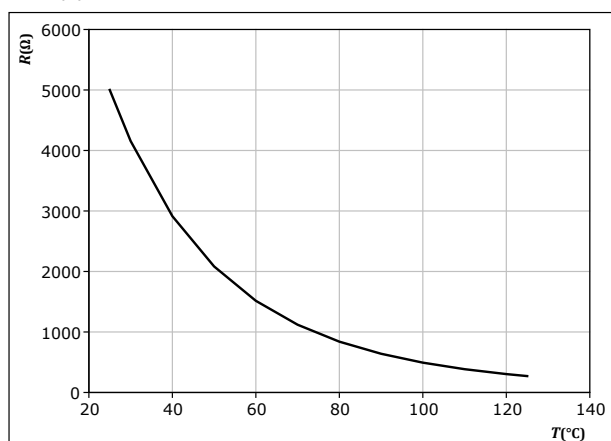
Thermistor Characteristics

figure 7.

Thermistor

Typical NTC characteristic as function of temperature

$$R_T = f(T)$$





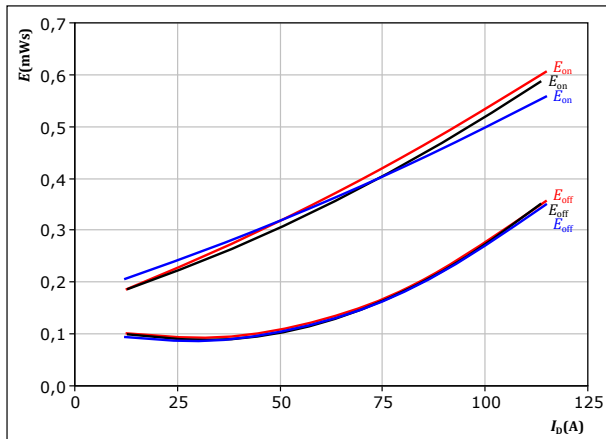
Vincotech

10-EY124PA016ME-LP49F18T datasheet

Inverter Switching Characteristics

figure 8. MOSFET

Typical switching energy losses as a function of drain current
 $E = f(I_D)$

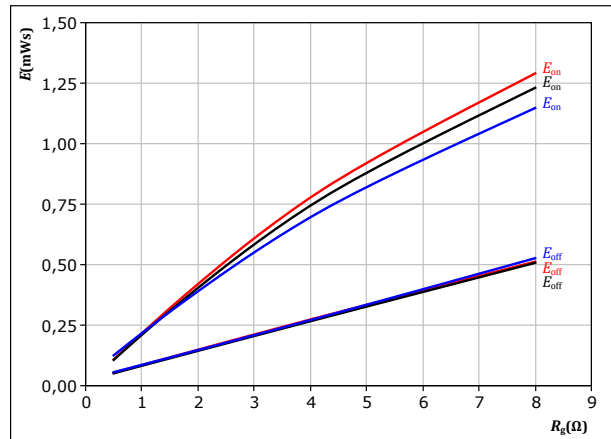


With an inductive load at

$V_{DS} = 600 \text{ V}$
 $V_{GS} = -4/15 \text{ V}$
 $R_{gon} = 2 \text{ } \Omega$
 $R_{goff} = 2 \text{ } \Omega$
 $T_j: 25 \text{ } ^\circ\text{C}$
 $125 \text{ } ^\circ\text{C}$
 $150 \text{ } ^\circ\text{C}$

figure 9. MOSFET

Typical switching energy losses as a function of MOSFET turn on gate resistor
 $E = f(R_g)$

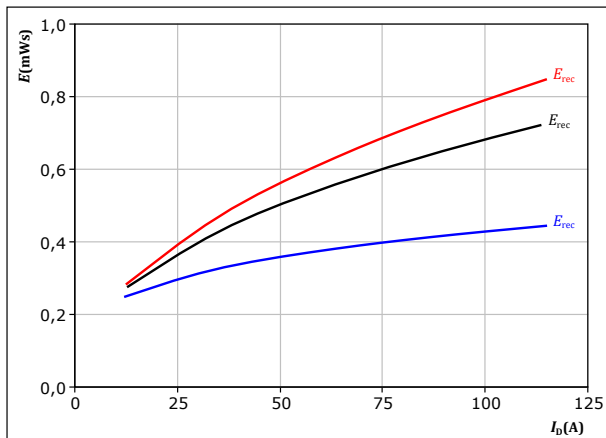


With an inductive load at

$V_{DS} = 600 \text{ V}$
 $V_{GS} = -4/15 \text{ V}$
 $I_D = 64 \text{ A}$
 $T_j: 25 \text{ } ^\circ\text{C}$
 $125 \text{ } ^\circ\text{C}$
 $150 \text{ } ^\circ\text{C}$

figure 10. MOSFET

Typical reverse recovered energy loss as a function of drain current
 $E_{rec} = f(I_D)$

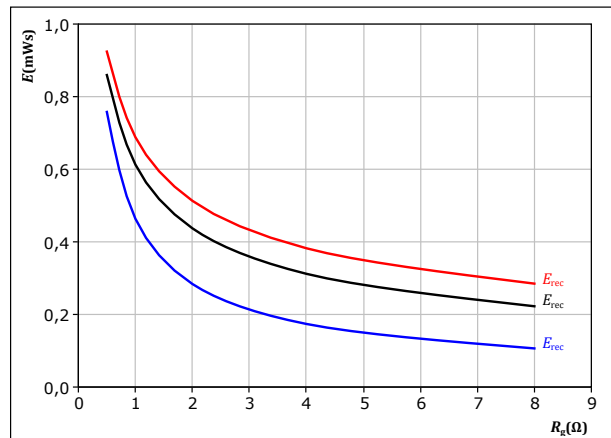


With an inductive load at

$V_{DS} = 600 \text{ V}$
 $V_{GS} = -4/15 \text{ V}$
 $R_{gon} = 2 \text{ } \Omega$
 $T_j: 25 \text{ } ^\circ\text{C}$
 $125 \text{ } ^\circ\text{C}$
 $150 \text{ } ^\circ\text{C}$

figure 11. MOSFET

Typical reverse recovered energy loss as a function of MOSFET turn on gate resistor
 $E_{rec} = f(R_g)$



With an inductive load at

$V_{DS} = 600 \text{ V}$
 $V_{GS} = -4/15 \text{ V}$
 $I_D = 64 \text{ A}$
 $T_j: 25 \text{ } ^\circ\text{C}$
 $125 \text{ } ^\circ\text{C}$
 $150 \text{ } ^\circ\text{C}$



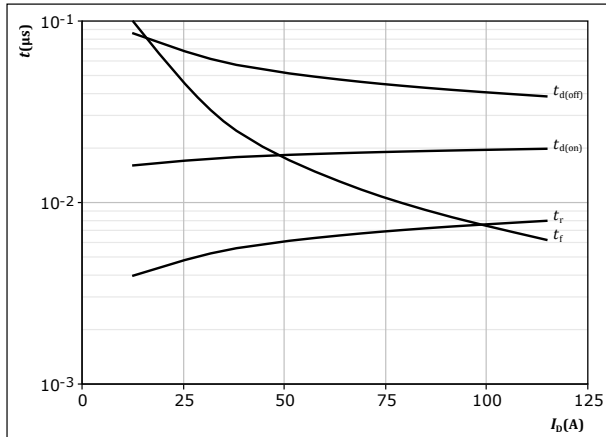
Vincotech

10-EY124PA016ME-LP49F18T datasheet

Inverter Switching Characteristics

figure 12. MOSFET

Typical switching times as a function of drain current
 $t = f(I_D)$

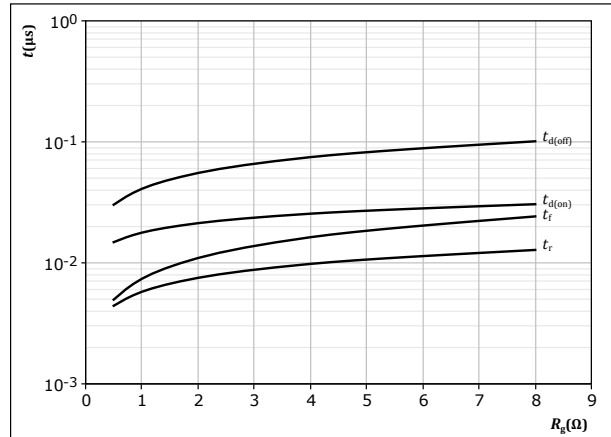


With an inductive load at

$T_j = 150$ °C
 $V_{DS} = 600$ V
 $V_{GS} = -4/15$ V
 $R_{gon} = 2$ Ω
 $R_{goff} = 2$ Ω

figure 13. MOSFET

Typical switching times as a function of MOSFET turn on gate resistor
 $t = f(R_g)$

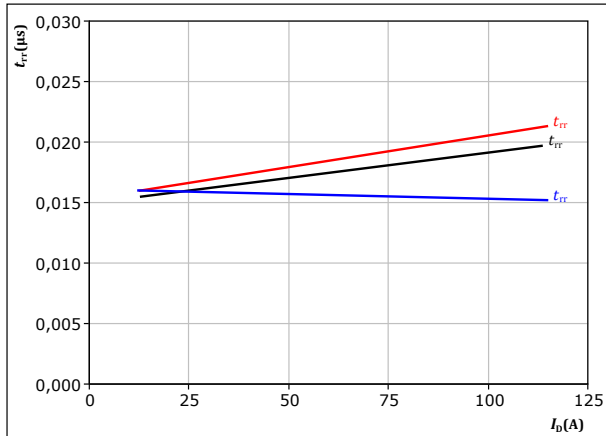


With an inductive load at

$T_j = 150$ °C
 $V_{DS} = 600$ V
 $V_{GS} = -4/15$ V
 $I_D = 64$ A

figure 14. MOSFET

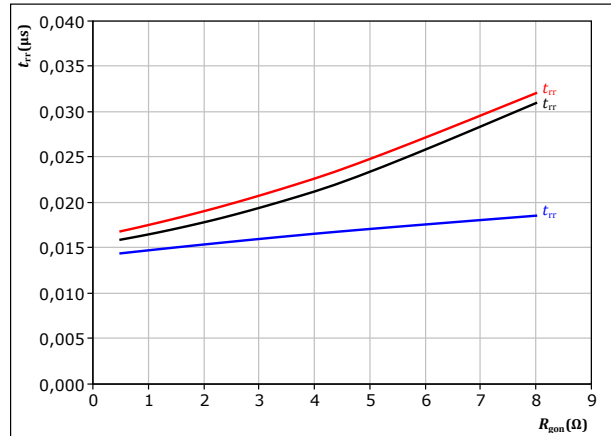
Typical reverse recovery time as a function of drain current
 $t_{rr} = f(I_D)$



At $V_{DS} = 600$ V
 $V_{GS} = -4/15$ V
 $R_{gon} = 2$ Ω
 $T_j: 25$ °C (blue)
 125 °C (black)
 150 °C (red)

figure 15. MOSFET

Typical reverse recovery time as a function of MOSFET turn on gate resistor
 $t_{rr} = f(R_{gon})$



At $V_{DS} = 600$ V
 $V_{GS} = -4/15$ V
 $I_D = 64$ A
 $T_j: 25$ °C (blue)
 125 °C (black)
 150 °C (red)



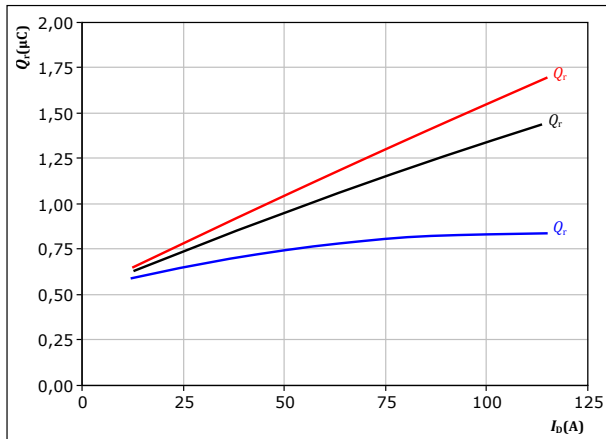
Vincotech

Inverter Switching Characteristics

figure 16. MOSFET

Typical recovered charge as a function of drain current

$$Q_r = f(I_D)$$

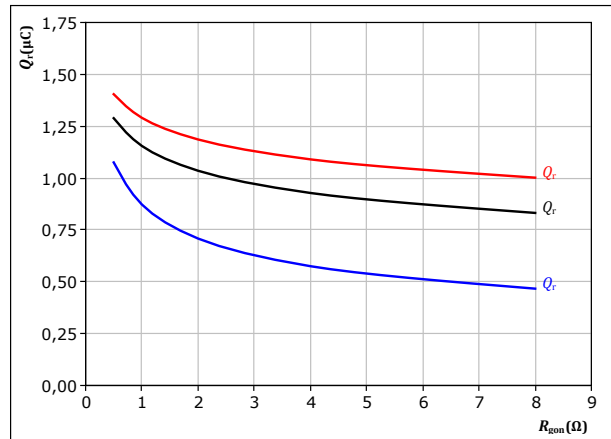


At $V_{DS} = 600$ V
 $V_{GS} = -4/15$ V
 $R_{gon} = 2$ Ω
 T_j : 25 °C
125 °C
150 °C

figure 17. MOSFET

Typical recovered charge as a function of MOSFET turn on gate resistor

$$Q_r = f(R_{gon})$$

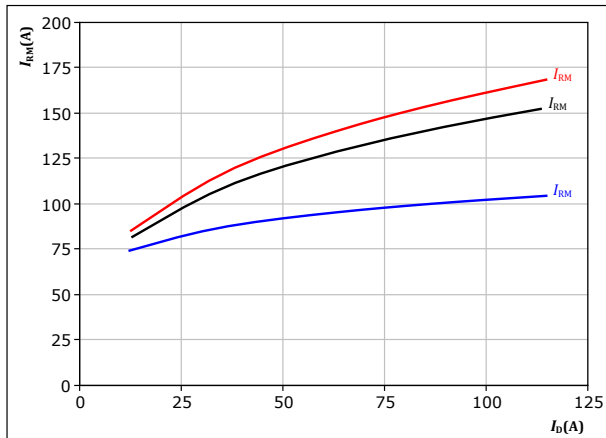


At $V_{DS} = 600$ V
 $V_{GS} = -4/15$ V
 $I_D = 64$ A
 T_j : 25 °C
125 °C
150 °C

figure 18. MOSFET

Typical peak reverse recovery current as a function of drain current

$$I_{RM} = f(I_D)$$

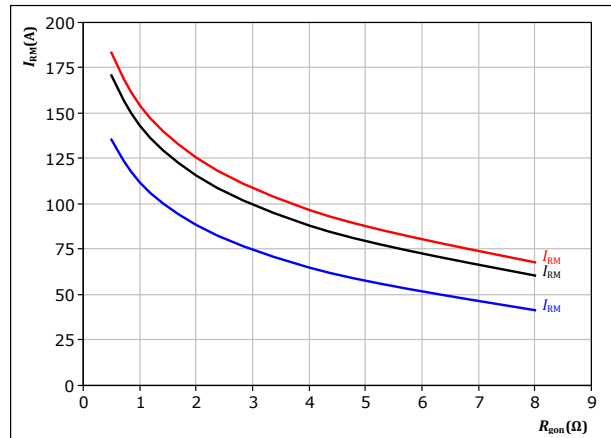


At $V_{DS} = 600$ V
 $V_{GS} = -4/15$ V
 $R_{gon} = 2$ Ω
 T_j : 25 °C
125 °C
150 °C

figure 19. MOSFET

Typical peak reverse recovery current as a function of MOSFET turn on gate resistor

$$I_{RM} = f(R_{gon})$$



At $V_{DS} = 600$ V
 $V_{GS} = -4/15$ V
 $I_D = 64$ A
 T_j : 25 °C
125 °C
150 °C

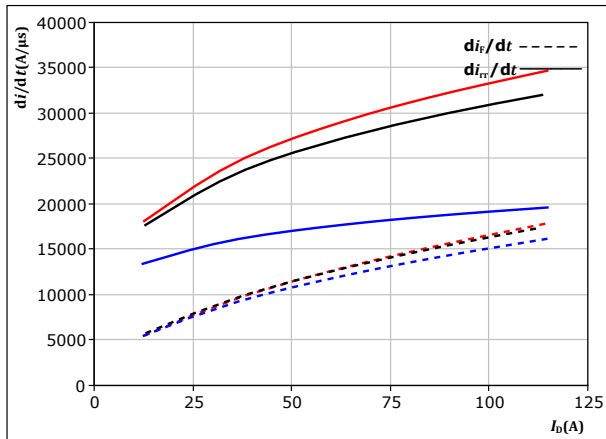


Vincotech

Inverter Switching Characteristics

figure 20. MOSFET

Typical rate of fall of forward and reverse recovery current as a function of drain current
 $di_f/dt, di_r/dt = f(I_D)$

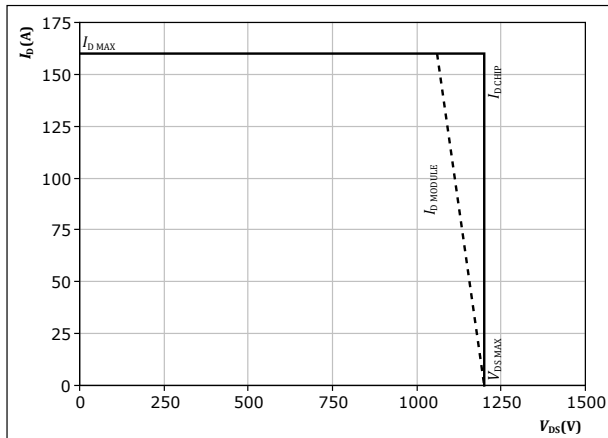


At $V_{DS} = 600$ V
 $V_{GS} = -4/15$ V
 $R_{gon} = 2$ Ω
 $T_j = 25$ °C
125 °C
150 °C

figure 22. MOSFET

Reverse bias safe operating area

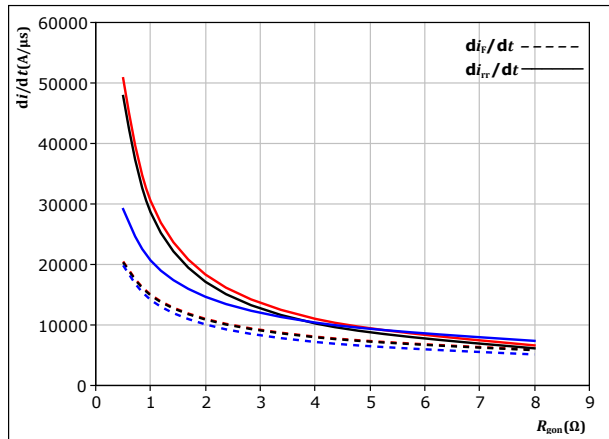
$I_D = f(V_{DS})$



At $T_j = 150$ °C
 $R_{gon} = 2$ Ω
 $R_{goff} = 2$ Ω

figure 21. MOSFET

Typical rate of fall of forward and reverse recovery current as a function of turn on gate resistor
 $di_f/dt, di_r/dt = f(R_{gon})$



At $V_{DS} = 600$ V
 $V_{GS} = -4/15$ V
 $I_D = 64$ A
 $T_j = 25$ °C
125 °C
150 °C



Vincotech

10-EY124PA016ME-LP49F18T datasheet

Inverter Switching Definitions

figure 23. MOSFET

Turn-off Switching Waveforms & definition of t_{doff} , t_{Eoff} (t_{Eoff} = integrating time for E_{off})



figure 24. MOSFET

Turn-on Switching Waveforms & definition of t_{don} , t_{Eon} (t_{Eon} = integrating time for E_{on})



figure 25. MOSFET

Turn-off Switching Waveforms & definition of t_f

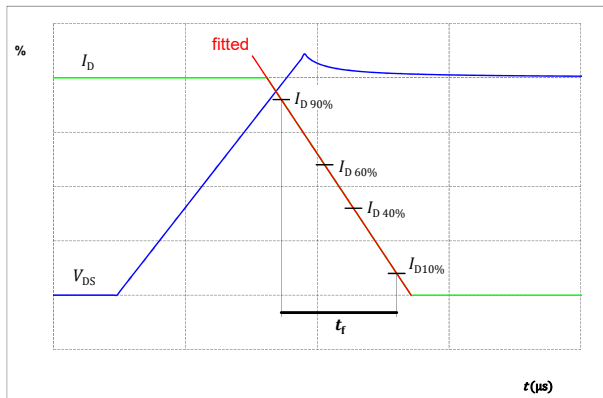
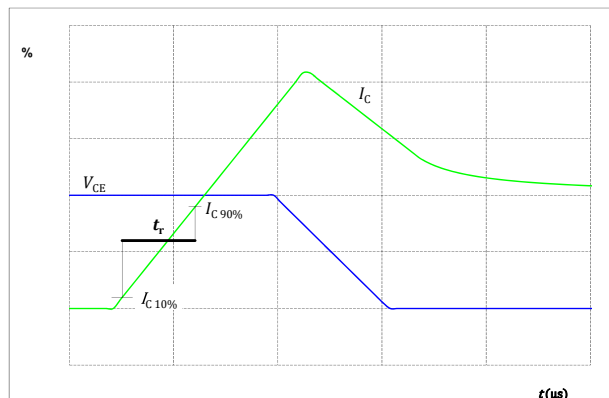


figure 26. MOSFET

Turn-on Switching Waveforms & definition of t_r





Vincotech

Inverter Switching Definitions

figure 27. FWD

Turn-off Switching Waveforms & definition of t_{tr}

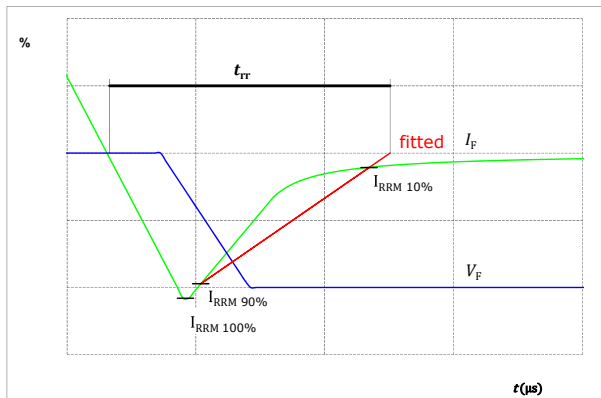


figure 28. FWD

Turn-on Switching Waveforms & definition of t_{Qr} (t_{Qr} = integrating time for Q_r)

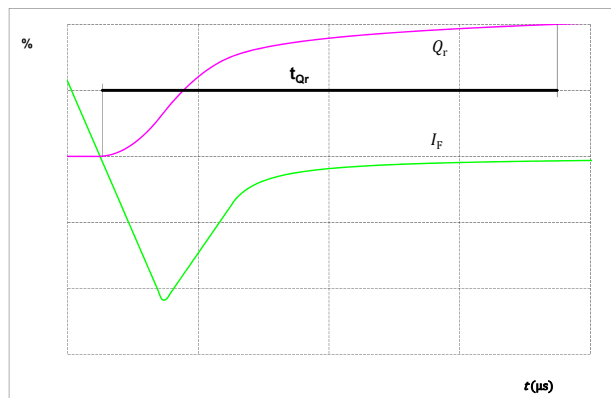
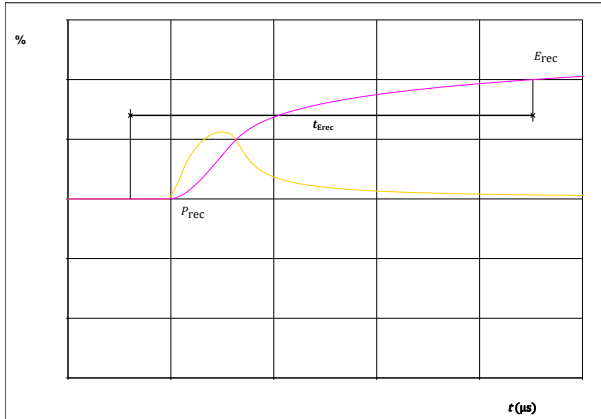


figure 29. FWD

Turn-on Switching Waveforms & definition of t_{Erec} (t_{Erec} = integrating time for E_{rec})





Vincotech

10-EY124PA016ME-LP49F18T

datasheet

Ordering Code	
Version	Ordering Code
Without thermal paste	10-EY124PA016ME-LP49F18T
With thermal paste (5,2 W/mK, PTM6000HV)	10-EY124PA016ME-LP49F18T-/7/

Marking						
	Text	Name	Date code	UL & VIN	Lot	Serial
		NN-NNNNNNNNNNNNNNNN- TTTTTVV	WWYY	UL VIN	LLLLL	SSSS
	Datamatrix	Type&Ver TTTTTTTV	Lot number LLLLL	Serial SSSS	Date code WWYY	

Outline

Pin table [mm]

Pin	X	Y	Function
1	3,2	0	AC2
2	0	0	AC2
3	3,2	3,2	AC2
4	0	3,2	AC2
5	3,2	9,6	S3
6	3,2	12,8	G3
7	3,2	25,6	S1
8	0	25,6	G1
9	3,2	32	AC1
10	0	32	AC1
11	3,2	35,2	AC1
12	0	35,2	AC1
13	3,2	48	T1
14	0	48	T2
15	32	48	DC-1
16	32	44,8	DC-1
17	32	41,6	DC-1
18	28,8	41,6	DC-1
19	28,8	48	G2
20	28,8	44,8	S2
21	32	32	DC+
22	28,8	32	DC+
23	32	28,8	DC+
24	32	25,6	DC+
25	32	22,4	DC+
26	32	19,2	DC+
27	32	16	DC+
28	28,8	16	DC+
29	32	6,4	DC-2
30	28,8	6,4	DC-2
31	32	3,2	DC-2
32	32	0	DC-2
33	28,8	3,2	S4
34	28,8	0	G4

center of press-fit pin head
pin head type T1 PCB pushed through hole Ø 1mm ±0.09 I-0.06
for further PCB design rules refer to the latest handling instruction

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

1008 ±0.1
8.4 ±0.5

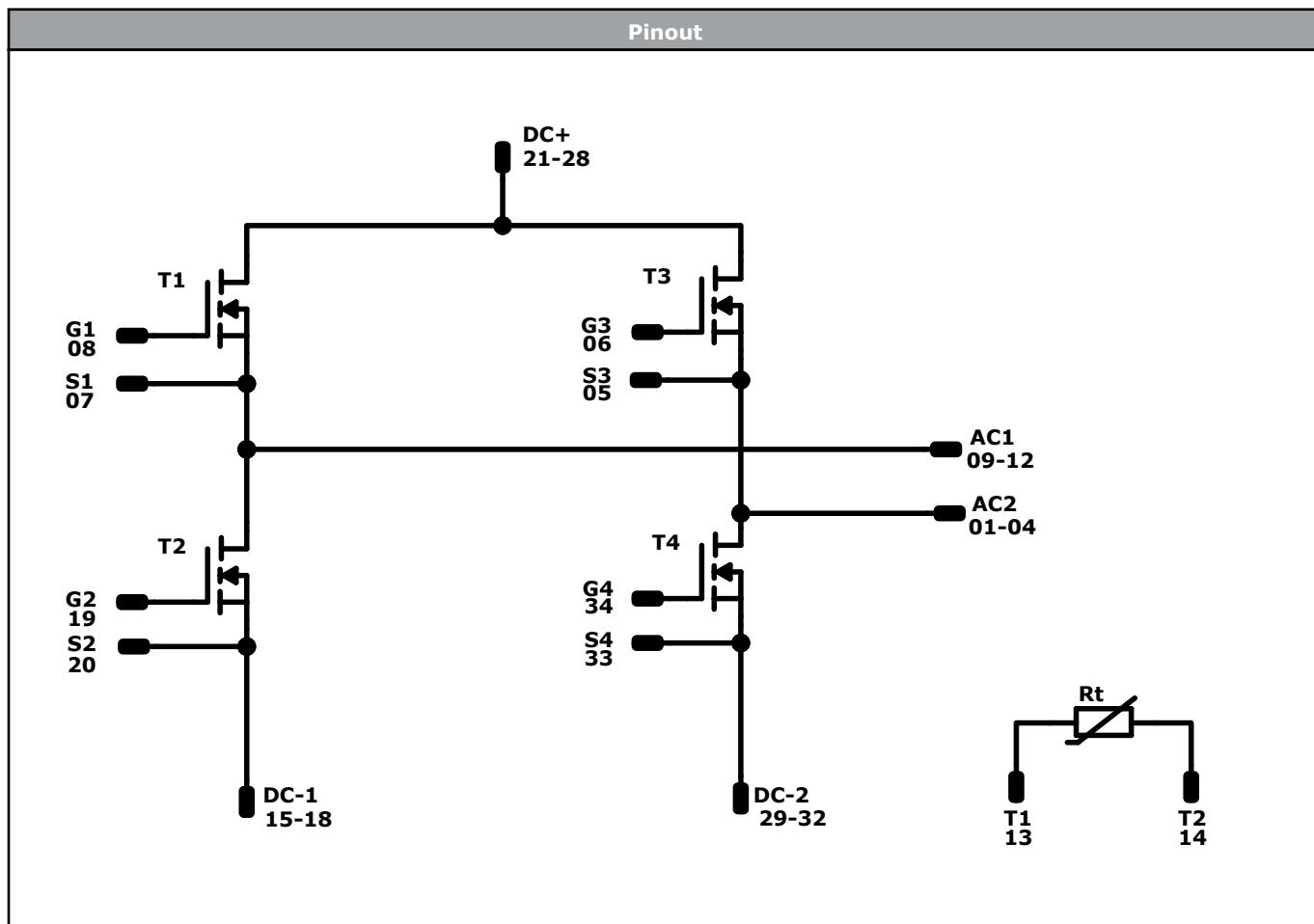
1008 ±0.1
8.4 ±0.5

1008 ±0.1



Vincotech

10-EY124PA016ME-LP49F18T
datasheet



Identification					
ID	Component	Voltage	Current	Function	Comment
T2, T1, T4, T3	MOSFET	1200 V	16 mΩ	Inverter Switch	
Rt	Thermistor			Thermistor	



Vincotech

10-EY124PA016ME-LP49F18T
datasheet

Packaging instruction				
Standard packaging quantity (SPQ) 100	>SPQ	Standard	<SPQ	Sample

Handling instruction
Handling instructions for <i>flow</i> E2 packages see vincotech.com website.

Package data
Package data for <i>flow</i> E2 packages see vincotech.com website.

Vincotech thermistor reference
See Vincotech thermistor reference table at vincotech.com website.

UL recognition and file number
This device is UL 1557 recognized under E192116 up to a junction temperature under switching condition $T_{j,sp}=175^{\circ}\text{C}$ and up to 3500VAC/1min isolation voltage. For more information see vincotech.com website.



Document No.:	Date:	Modification:	Pages
10-EY124PA016ME-LP49F18T-D2-14	25 Apr. 2025	Update MosFET characteristics, module is unchanged	

DISCLAIMER

The information, specifications, procedures, methods and recommendations herein (together "information") are presented by Vincotech to reader in good faith, are believed to be accurate and reliable, but may well be incomplete and/or not applicable to all conditions or situations that may exist or occur. Vincotech reserves the right to make any changes without further notice to any products to improve reliability, function or design. No representation, guarantee or warranty is made to reader as to the accuracy, reliability or completeness of said information or that the application or use of any of the same will avoid hazards, accidents, losses, damages or injury of any kind to persons or property or that the same will not infringe third parties rights or give desired results. It is reader's sole responsibility to test and determine the suitability of the information and the product for reader's intended use.

LIFE SUPPORT POLICY

Vincotech products are not authorised for use as critical components in life support devices or systems without the express written approval of Vincotech.

As used herein:

1. Life support devices or systems are devices or systems which, (a) are intended for surgical implant into the body, or (b) support or sustain life, or (c) whose failure to perform when properly used in accordance with instructions for use provided in labelling can be reasonably expected to result in significant injury to the user.
2. A critical component is any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.